



## Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



www.hittite.com

www.analog.com

THIS PAGE INTENTIONALLY LEFT BLANK





## HMC241LP3 / 241LP3E

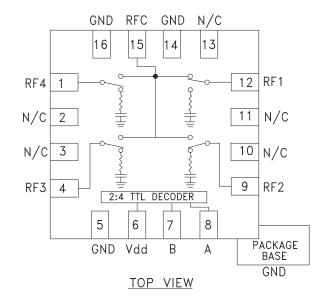
#### GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz

#### **Typical Applications**

The HMC241LP3 / HMC241LP3E is ideal for:

- Base Stations & Repeaters
- WLAN, WIMAX & WiBro
- CATV / DBS
- Test Equipment

#### **Functional Diagram**



#### Features

High Isolation: 43 dB @ 2 GHz Low Insertion Loss: 0.7 dB @ 2 GHz Single Positive Supply: Vdd = +5V Integrated 2:4 TTL Decoder 3x3 mm SMT Package

#### **General Description**

The HMC241LP3 & HMC241LP3E are general purpose non-reflective SP4T switches in low cost leadless surface mount packages. Covering DC - 4 GHz, this switch offers high isolation and has a low insertion loss of 0.7 dB at 2 GHz. The switch offers a single positive bias and true TTL/CMOS compatibility. A 2:4 decoder is integrated on the switch requiring only 2 control lines and a positive bias to select each path, replacing 4 to 8 control lines normally required by GaAs SP4T switches.

Parameter	Frequency	Min.	Тур.	Max.	Units
Insertion Loss	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 4.0 GHz		0.6 0.7 0.9 1.2	0.9 1.0 1.2 1.5	dB dB dB dB
Isolation	DC - 1.0 GHz DC - 2.0 GHz DC - 2.5 GHz DC - 4.0 GHz	40 38 35 25	45 43 40 30		dB dB dB dB
Return Loss "On State"	DC - 2.5 GHz DC - 4.0 GHz		18 12		dB dB
Return Loss RF1-4 "Off State"	0.3 - 4.0 GHz		12		dB
Input Power for 1dB Compression	0.3 - 4.0 GHz		26		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)	0.3 - 4.0 GHz		45		dBm
Switching Characteristics	0.3 - 4.0 GHz				
tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)			40 100		ns ns

#### **Electrical Specifications**, $T_A = +25^{\circ}$ C, For TTL Control and Vdd = +5V in a 50 Ohm System

For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

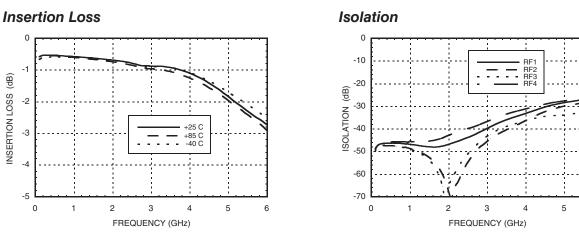


### HMC241LP3 / 241LP3E

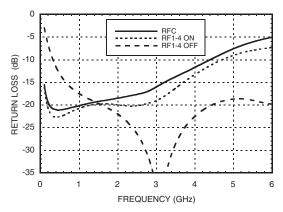
# **RoHS**√

INSERTION LOSS (dB)

#### GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz



**Return Loss** 



#### **Bias Voltage & Current**

Vdd Range = +5.0 Vdc ± 10%		
Vdd (Vdc)	ldd (Typ.) (mA)	ldd (Max.) (mA)
+5.0	2.7	5.0

#### **TTL/CMOS Control Voltages**

State	Bias Condition
Low	0 to +0.8 Vdc @ 5uA Typ.
High	+2.0 to +5.0 Vdc @ 70 uA Typ.

NOTE: DC Blocking capacitors are required at ports RFC and RF1, 2, 3, 4.

#### **Truth Table**

Control Input		Signal Path State	
А	В	RFC to:	
LOW	LOW	RF1	
HIGH	LOW	RF2	
LOW	HIGH	RF3	
HIGH	HIGH	RF4	

## 10

6



## HMC241LP3 / 241LP3E



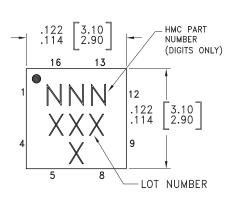
#### GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz

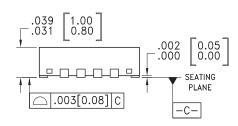
#### Absolute Maximum Ratings

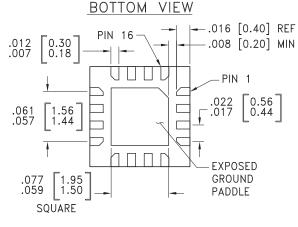
Bias Voltage Range (Vdd)	+7.0 Vdc
Control Voltage Range (A & B)	-0.5V to Vdd +1 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	200 °C/W
Thermal Resistance (Terminated Path)	240 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power Vdd = +5 Vdc	+20 dBm (0.05 - 0.5 GHz) +27 dBm (0.5 - 4.0 GHz)



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS







1. LEADFRAME MATERIAL: COPPER ALLOY

2. DIMENSIONS ARE IN INCHES [MILLIMETERS]

3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE

 PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
PACKAGE WARP SHALL NOT EXCEED 0.05mm.

6. ALL N/C LEADS, GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

#### **Package Information**

Part Number	Package Body Material	Leadframe Plating	MSL Rating	Package Marking [3]
HMC241LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 <sup>[1]</sup>	241 XXXX
HMC241LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% Matte Tin	MSL1 <sup>[2]</sup>	<u>241</u> XXXX

[1] Max peak reflow temperature of 235  $^\circ\text{C}$ 

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX



## HMC241LP3 / 241LP3E



#### GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz

#### **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 4, 9, 12, 15	RF4, RF3, RF2, RF1, RFC	This Pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required.	
2, 3, 10, 11, 13	N/C	This pin should be connected to PCB RF ground to maximize isolation.	
5, 14, 16	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	
6	Vdd	Supply Voltage +5V ± 10%	5pF
7	В	See truth table and control voltage table.	500 80K
8	A	See truth table and control voltage table.	



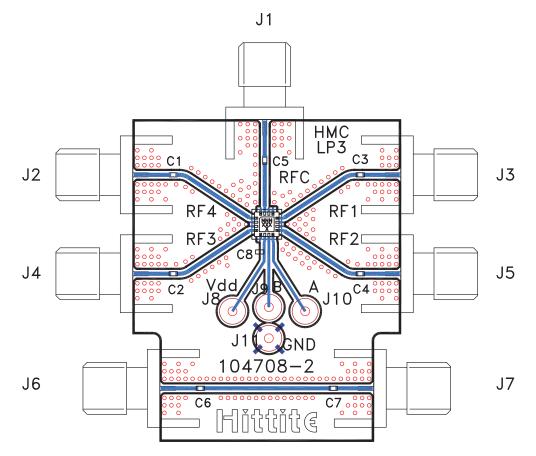
### HMC241LP3 / 241LP3E

MICROWAVE CORPORATION V01.0905



#### GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz

**Evaluation PCB** 



#### List of Materials for Evaluation PCB 108333 [1]

Item	Description	
J1 - J7	PCB Mount SMA RF Connector	
J8 - J11	DC Pin	
C1 - C7	100 pF Capacitor, 0402 Pkg.	
C8	10k pF Capacitor, 0603 Pkg.	
U1	HMC241LP3 / HMC241LP3E SP4T Switch	
PCB [2]	104708 Evaluation PCB	

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and package bottom should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.





GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 4 GHz

HMC241LP3 / 241LP3E

Notes:

### **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Analog Devices Inc.: HMC241LP3 108333-HMC241LP3 HMC241LP3ETR HMC241LP3E